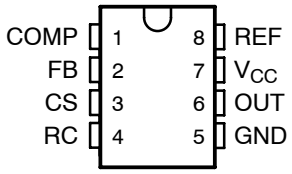
- **Controlled Baseline**
  - **One Assembly**
  - **One Test Site**
  - **One Fabrication Site**
- **Extended Temperature Performance of –55°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product Change Notification**
- **Qualification Pedigree†**
- **ESD Protection Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **100 μA Typical Starting Supply Current**
- **500 μA Typical Operating Supply Current**

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- **Operation to 1 MHz**
- **Internal Soft Start**
- **Internal Fault Soft Start**
- **Internal Leading-Edge Blanking of the Current Sense Signal**
- **1 Amp Totem-Pole Output**
- **70 ns Typical Response from Current-Sense to Gate Drive Output**
- **1.5% Tolerance Voltage Reference**
- **Same Pinout as UC3842 and UC3842A**

D PACKAGE
(TOP VIEW)



description

The UCC2800/1/2/3/4/5 family of high-speed, low-power integrated circuits contain all of the control and drive components required for off-line and dc-to-dc fixed frequency current-mode switching power supplies with minimal parts count.

These devices have the same pin configuration as the UC2842/3/4/5 family and also offer the added features of internal full-cycle soft start and internal leading-edge blanking of the current-sense input.

The UCC2800/1/2/3/4/5 family offers choice of maximum duty cycle and critical voltage levels. Lower reference parts such as the UCC2803 and UCC2805 fit best into battery operated systems, while the higher reference and the higher UVLO hysteresis of the UCC2802 and UCC2804 make these ideal choices for use in off-line power supplies.

PART NUMBER	MAXIMUM DUTY CYCLE	REFERENCE VOLTAGE	TURN-ON THRESHOLD	TURN-OFF THRESHOLD
UCC2800	100%	5 V	7.2 V	6.9 V
UCC2801	50%	5 V	9.4 V	7.4 V
UCC2802	100%	5 V	12.5 V	8.3 V
UCC2803	100%	4 V	4.1 V	3.6 V
UCC2804	50%	5 V	12.5 V	8.3 V
UCC2805	50%	4 V	4.1 V	3.6 V

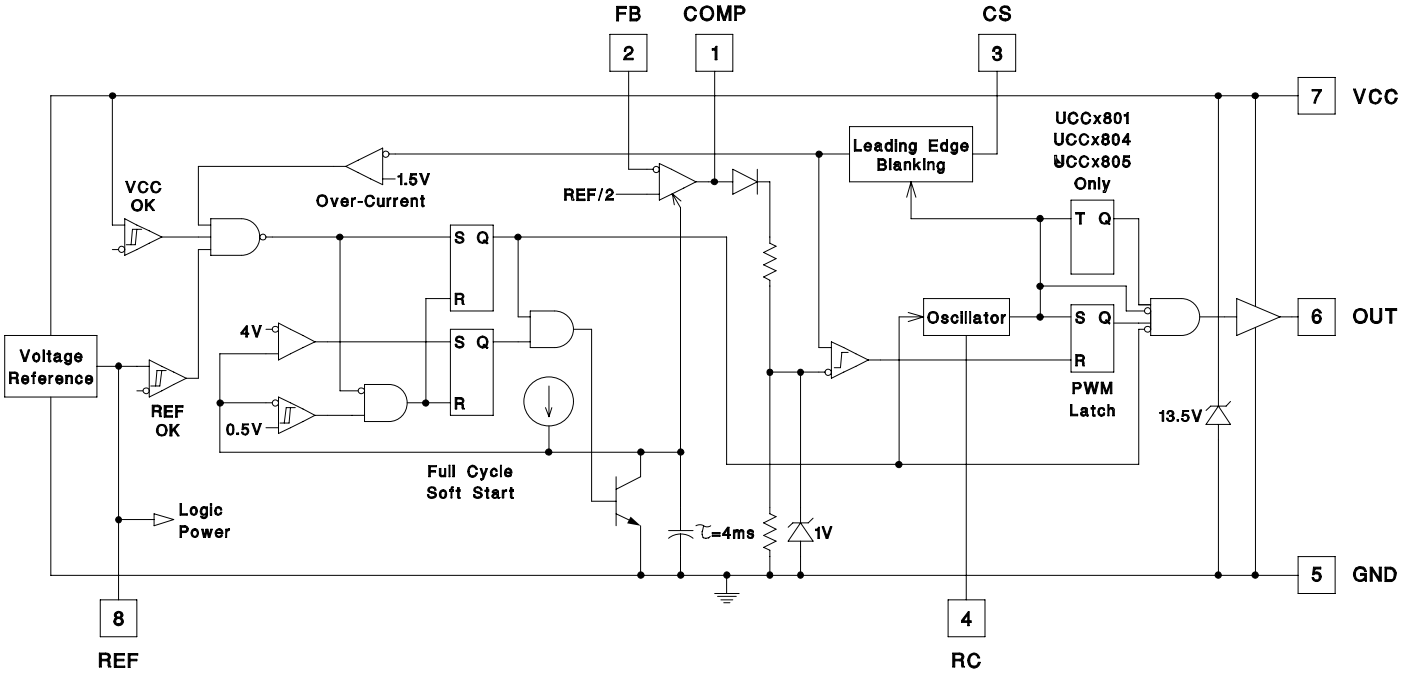
ORDERING INFORMATION†

T_A	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOP – D	Tape and reel	UCC2800QDREP	2800EP
			UCC2801QDREP	2801EP
			UCC2802QDREP	2802EP
			UCC2803QDREP	2803EP
			UCC2804QDREP	2804EP
			UCC2805QDREP	2805EP
–55°C to 125°C	SOP – D	Tape and reel	UCC2800MDREP	2800EP
			UCC2801MDREP	2801EP
			UCC2803MDREP	2803EP

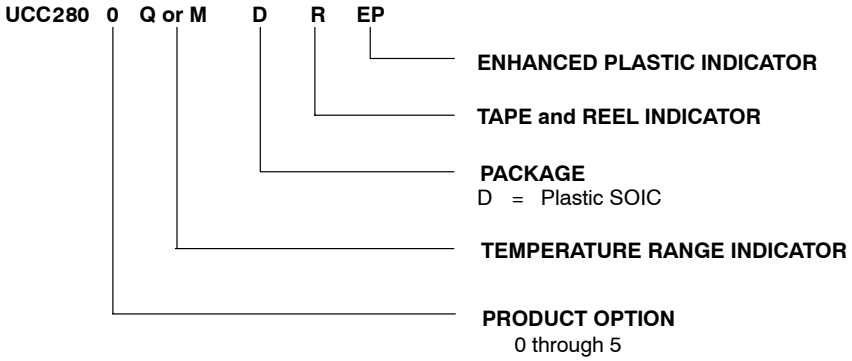
† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

‡ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

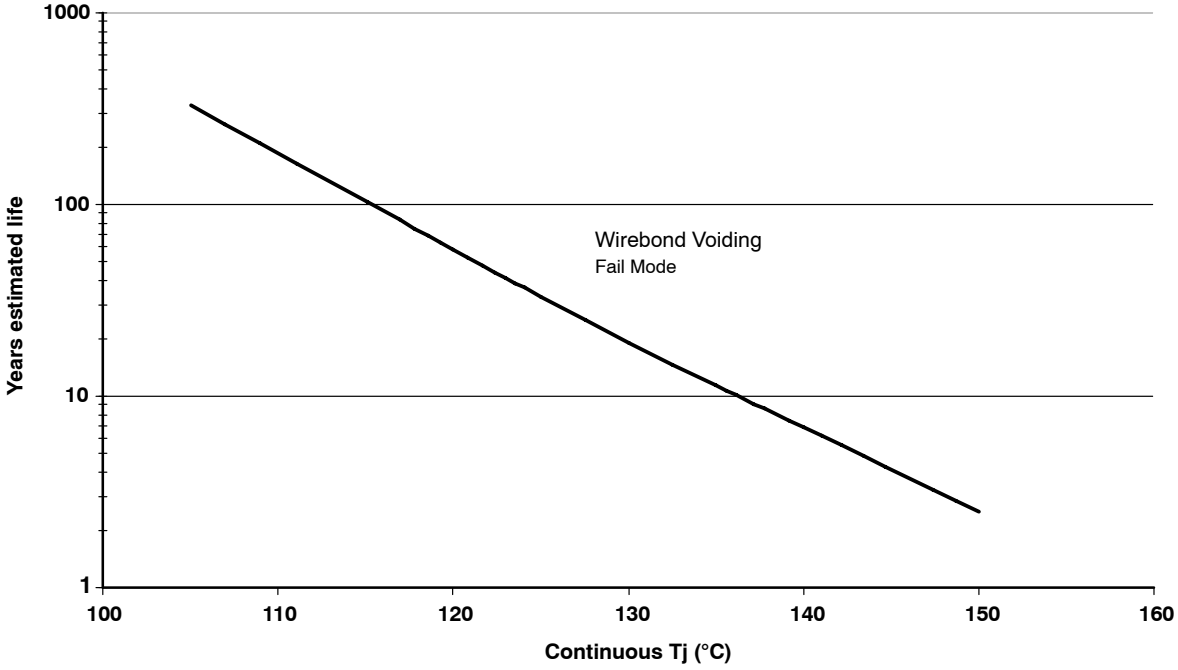
block diagram



Ordering Information



UCC280XXD–EP Operating Life Derating Chart



NOTES: A. See datasheet for Absolute Maximum and Minimum Recommended Operating Conditions
B. Silicon operating life design Goal is 10 @ 105°C junction temperature (does not include package interconnect life).
C. Enhanced plastic product disclaimer applies.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†‡

V_{CC} voltage § . . . . . 12 V
V_{CC} current § . . . . . 30 mA
Output current, I_O . . . . . ±1 A
Output energy (capacitive load) . . . . . 20 µJ
Analog inputs (FB, CS, RC, COMP) . . . . . –0.3 V to the lesser of 6.3 V or VCC + 0.3 V
Power dissipation at T_A < +25°C (D package) . . . . . 0.65 W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 in) from case for 10s . . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

‡ Unless otherwise indicated, voltages are reference to ground and currents are positive into and negative out of the specified terminals.

§ In normal operation, V_{CC} is powered through a current limiting resistor. Absolute maximum of 12 V applies when V_{CC} is driven from a low impedance source such that I_{CC} does not exceed 30 mA (which includes gate drive current requirement).

electrical characteristics, T_A = –40°C to 125°C for Q temp and T_A= –55°C to 125°C for M temp, V_{CC} = 10 V (see Note 1), R_T = 100 kΩ from REF to RC, C_T = 330 pF from RC to GND, 0.1 F capacitor from V_{CC} to GND, 0.1 F capacitor from V_{REF} to GND and T_A = T_J (unless otherwise stated)

PARAMETER	TEST CONDITIONS		UCC280XQ, UCC280XM			UNIT
			MIN	TYP	MAX	
Reference Section						
Output voltage	T_J = 25°C, I = 0.2 mA	UCC2800/01/02/04	4.925	5	5.075	V
		UCC2803/05	3.94	4	4.06	
Load regulation voltage	I = 0.2 mA to 5 mA			10	30	mV
Line regulation voltage	V_{CC} = 10 V to clamp	T_J = 25°C			1.9	mV/V
		T_J = –40°C to 125°C and TJ = –55°C to 125°C			2.5	
Total variation voltage	See Note 5	UCC2800/01/02/04	4.88	5	5.1	V
		UCC2803/05	3.9	4	4.08	
Output noise voltage	f = 10 Hz to 10 kHz, See Note 7	T_J = 25°C		130		µV
Long term stability	1000 hours, See Note 7	T_A = 125°C		5		mV
Output short-circuit current			–5		–35	mA

electrical characteristics, T_A = –40°C to 125°C for Q temp and T_A= –55°C to 125°C for M temp, V_{CC} = 10 V (see Note 1), R_T = 100 kΩ from REF to RC, C_T = 330 pF from RC to GND, 0.1 F capacitor from V_{CC} to GND, 0.1 F capacitor from V_{REF} to GND and T_A = T_J (unless otherwise stated)

PARAMETER	TEST CONDITIONS		UCC280XQ, UCC280XM			UNIT
			MIN	TYP	MAX	
Oscillator Section						
Oscillator frequency	See Note 2	UCC2800/01/02/04	40	46	52	kHz
		UCC2803/05	26	31	36	
Temperature stability	See Note 7			2.5%		
Amplitude peak-to-peak			2.25	2.4	2.55	V
Oscillator peak voltage				2.45		V
Error Amplifier Section						
Input voltage	COMP = 2.5 V	UCC2800/01/02/04	2.44	2.5	2.56	V
	COMP = 2 V	UCC2803/05	1.95	2	2.05	
Input bias current			–1		1	μA
Open loop voltage gain			60	80		db
COMP sink current	FB = 2.7 V, COMP = 1.1 V		0.3		3.5	mA
COMP source current	FB = 1.8 V, COMP = REF – 1.2 V		–0.2	–0.5	–0.8	mA
Gain bandwidth product	See Note 7			2		MHz
PWM Section						
Maximum duty cycle		UCC2800/02/03	97%	99%	100%	
		UCC2801/04/05	48%	49%	50%	
Minimum duty cycle	COMP = 0 V				0	
Current Sense Section						
Gain	See Note 3		1.1	1.65	1.8	V/V
Maximum input signal	COMP = 5 V, See Note 4		0.9	1	1.1	V
Input bias current			–200		200	nA
CS blank time			50	100	150	ns
Overcurrent threshold voltage			1.42	1.55	1.68	V
COMP to CS offset voltage	CS = 0 V		0.45	0.9	1.35	V
Output Section (OUT)						
Low-level output voltage	I_{OUT} = 20 mA	All parts		0.1	0.4	V
	I_{OUT} = 200 mA	All parts		0.35	0.9	
	I_{OUT} = 50 mA, V_{CC} = 5 V	UCC2803/05		0.15	0.4	
	I_{OUT} = 20 mA, V_{CC} = 0 V	All parts		0.7	1.2	
High-level output voltage V_{SAT} (V_{CC} – OUT)	I_{OUT} = –20 mA	All parts		0.15	0.4	V
	I_{OUT} = –200 mA	All parts		1	1.9	
	I_{OUT} = –50 mA, V_{CC} = 5 V	UCC2803/05		0.4	0.9	
Rise time	C_L = 1 nF			41	70	ns
Fall time	C_L = 1 nF			44	75	ns

electrical characteristics, T_A = –40°C to 125°C for Q temp and T_A= –55°C to 125°C for M temp, V_{CC} = 10 V (see Note 1), R_T = 100 kΩ from REF to RC, C_T = 330 pF from RC to GND, 0.1 F capacitor from V_{CC} to GND, 0.1 F capacitor from V_{REF} to GND and T_A = T_J (unless otherwise stated)

PARAMETER	TEST CONDITIONS		UCC280XQ, UCC280XM			UNIT
			MIN	TYP	MAX	
Undervoltage Lockout Section						
Start threshold	See Note 6	UCC2800	6.6	7.2	7.8	V
		UCC2801	8.6	9.4	10.2	
		UCC2802/04	11.5	12.5	13.5	
		UCC2803/05	3.7	4.1	4.5	
Stop threshold	See Note 6	UCC2800	6.3	6.9	7.5	V
		UCC2801	6.8	7.4	8	
		UCC2802/04	7.6	8.3	9	
		UCC2803/05	3.2	3.6	4	
Start to stop hysteresis		UCC2800	0.12	0.3	0.48	V
		UCC2801	1.6	2	2.4	
		UCC2802/04	3.5	4.2	5.1	
		UCC2803/05	0.2	0.5	0.8	
Soft Start Section						
COMP rise time	FB = 1.8 V, Rise from 0.5 V to REF – 1 V			4	10	ms
Overall Section						
Start-up current	V_{CC} < Start threshold			0.1	0.2	mA
Operating supply current	FB = 0 V, CS = 0 V			0.5	1	mA
V_{CC} internal zener voltage	I_{CC} = 10 mA, See Note 6 and Note 8		12	13.5	15	V
V_{CC} internal zener voltage minus start threshold voltage	See Note 6	UCC2802/04	0.5	1		V

NOTES: 1. Adjust V_{CC} above the start threshold before setting at 10 V.
2. Oscillator frequency for the UCC2800, UCC2802, and UCC2803 is the output frequency.
Oscillator frequency for the UCC2801, UCC2804, and UCC2805 is twice the output frequency.
3. Gain is defined by: $A = \frac{\Delta V_{COMP}}{\Delta V_{CS}}$ $0 \le V_{CS} \le 0.8$ V
4. Parameter measured at trip point of latch with Pin 2 at 0 V
5. Total variation includes temperature stability and load regulation.
6. Start threshold, stop threshold, and zener shunt thresholds track one another.
7. Not production tested
8. The device is fully operating in clamp mode as the forcing current is higher than the normal operating supply current.

detailed terminal descriptions

COMP

COMP is the output of the error amplifier and the input of the PWM comparator.

Unlike other devices, the error amplifier in the UCC2800 family is a true, low output-impedance, 2 MHz operational amplifier. As such, the COMP terminal can both source and sink current. However, the error amplifier is internally current limited, so that one can command zero duty cycle by externally forcing COMP to GND.

The UCC2800 family features built-in full cycle soft start. Soft start is implemented as a clamp on the maximum COMP voltage.

CS

CS is the input to the current sense comparators. The UCC2800 family has two different current sense comparators - the PWM comparator and an overcurrent comparator.

The UCC2800 family contains digital current sense filtering, which disconnects the CS terminal from the current sense comparator during the 100 ns interval immediately following the rising edge of the OUT pin. This digital filtering, also called leading-edge blanking, means that in most applications, no analog filtering (RC filter) is required on CS. Compared to an external RC filter technique, the leading-edge blanking provides a smaller effective CS to OUT propagation delay. Note, however, that the minimum non-zero on-time of the OUT signal is directly affected by the leading-edge-blanking and the CS to OUT propagation delay.

The overcurrent comparator is only intended for fault sensing, and exceeding the over-current threshold will cause a soft start cycle.

FB

FB is the inverting input of the error amplifier. For best stability, keep FB lead length as short as possible and FB stray capacitance as small as possible.

ground (GND)

GND is reference ground and power ground for all functions on this part.

OUT

OUT is the output of a high-current power driver capable of driving the gate of a power MOSFET with peak currents exceeding 750 mA. OUT is actively held low when V_{CC} is below the UVLO threshold.

The high-current power driver consists of FET output devices, which can switch all of the way to GND and all of the way to V_{CC}. The output stage also provides a low impedance to overshoot and undershoot. This means that in many cases, external schottky clamp diodes are not required.

detailed descriptions (continued)

RC

RC is the oscillator timing pin. For fixed frequency operation, set timing capacitor charging current by connecting a resistor from REF to RC. Set frequency by connecting timing capacitor from RC to GND. For the best perfomance, keep the timing capacitor lead to GND as short and direct as possible. If possible, use separate ground traces for the timing capacitor and all other functions.

The frequency of oscillation can be estimated with the following equations:

$$\text{UCC2800/01/02/04}: F = \frac{1.5}{R \times C}$$

$$\text{UCC2803/UCC2805}: F = \frac{1.0}{R \times C} \quad (1)$$

where frequency is in Hz, resistance is in ohms, and capacitance is in farads. The recommended range of timing resistors is between 10k and 200k and timing capacitor is 100 pF to 1000 pF. Never use a timing resistor less than 10k.

To prevent noise problems, bypass V_{CC} to GND with a ceramic capacitor as close to the V_{CC} pin as possible. An electrolytic capacitor may also be used in addition to the ceramic capacitor.

voltage reference (REF)

REF is the voltage reference for the error amplifier and also for many other functions on the IC. REF is also used as the logic power supply for high speed switching logic on the IC.

When V_{CC} is greater than 1 V and less than the UVLO threshold, REF is pulled to ground through a 5 kΩ resistor. This means that REF can be used as a logic output indicating power system status. It is important for reference stability that REF is bypassed to GND with a ceramic capacitor as close to the pin as possible. An electrolytic capacitor may also be used in addition to the ceramic capacitor. A minimum of 0.1 μF ceramic is required. Additional REF bypassing is required for external loads greater than 2.5 mA on the reference.

To prevent noise problems with high speed switching transients, bypass REF to ground with a ceramic capacitor close to the IC package.

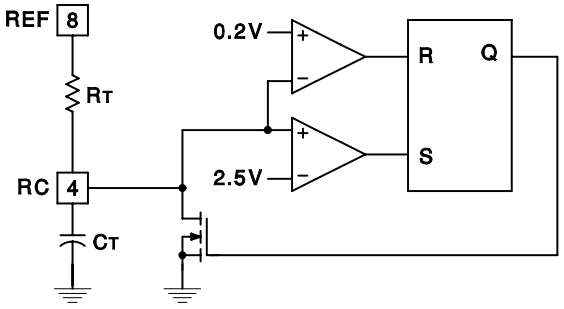
power (V_{CC})

V_{CC} is the power input connection for this device. In normal operation, V_{CC} is powered through a current limiting resistor. Although quiescent V_{CC} current is very low, total supply current will be higher, depending on the OUT current. Total V_{CC} current is the sum of quiescent V_{CC} current and the average OUT current. Knowing the operating frequency and the MOSFET gate charge (Q_g), average OUT current can be calculated from:

$$I_{OUT} = Q_g \times F \quad (2)$$

PARAMETER MEASUREMENT INFORMATION

Oscillator



The UCC3800/1/2/3/4/5 oscillator generates a sawtooth waveform on RC. The rise time is set by the time constant of R_T and C_T. The fall time is set by C_T and an internal transistor on-resistance of approximately 125. During the fall time, the output is off and the maximum duty cycle is reduced below 50% or 100% depending on the part number. Larger timing capacitors increase the discharge time and reduce the maximum duty cycle and frequency.

Figure 1

Error Amplifier Gain/Phase Response

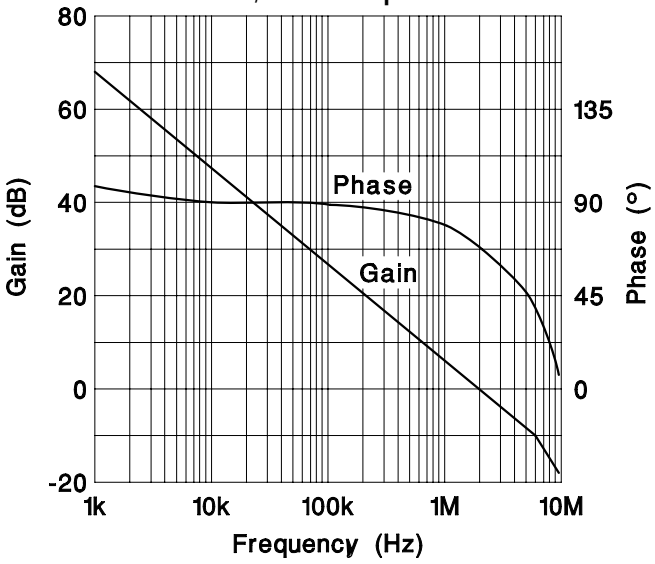


Figure 2

UCC1803/05 V_{REF} vs V_{CC}; I_{LOAD} = 0.5 mA

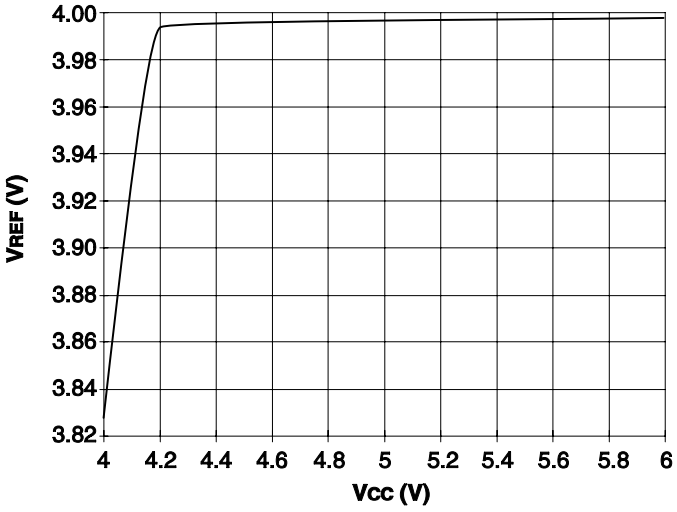


Figure 3

UCC1800/01/02/04 Oscillator Frequency vs R_T and C_T

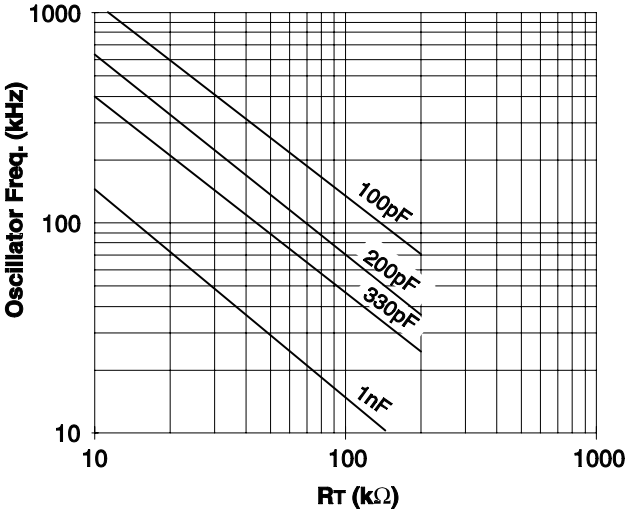


Figure 4

PARAMETER MEASUREMENT INFORMATION

UCC1803/05 Oscillator Frequency vs R_T and C_T

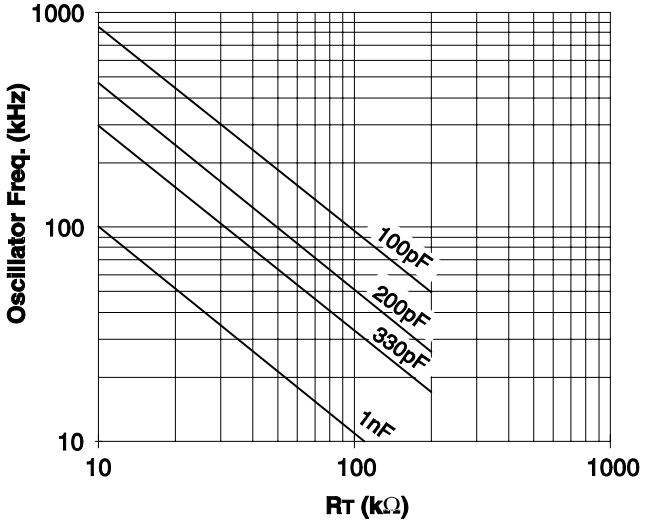


Figure 5

UCC1800/02/03 Maximum Duty Cycle vs Oscillator Frequency

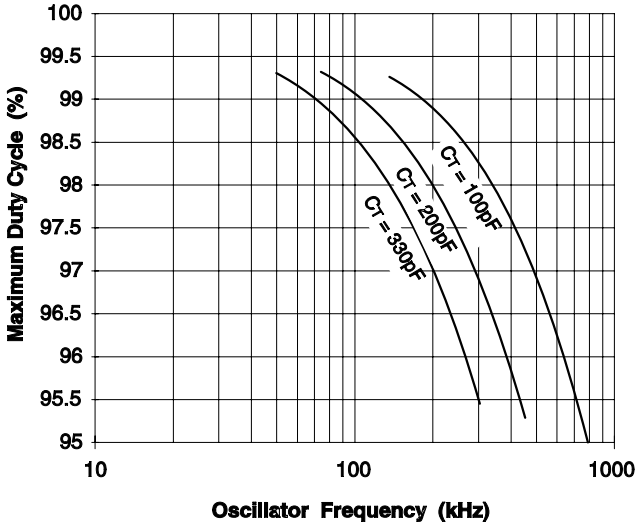


Figure 6

UCC1801/04/05 Maximum Duty Cycle vs Oscillator Frequency

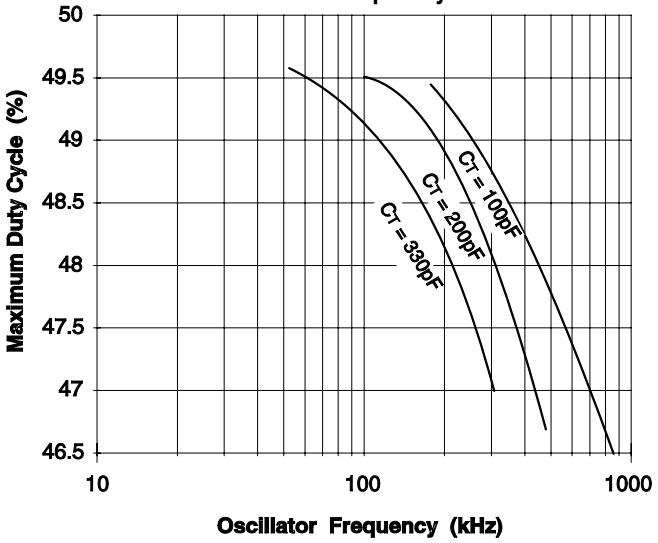


Figure 7

UCC1800 I_{CC} vs Oscillator Frequency

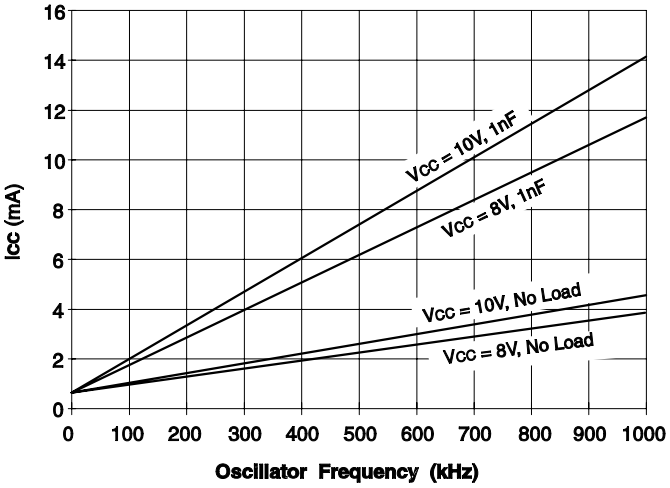


Figure 8

PARAMETER MEASUREMENT INFORMATION

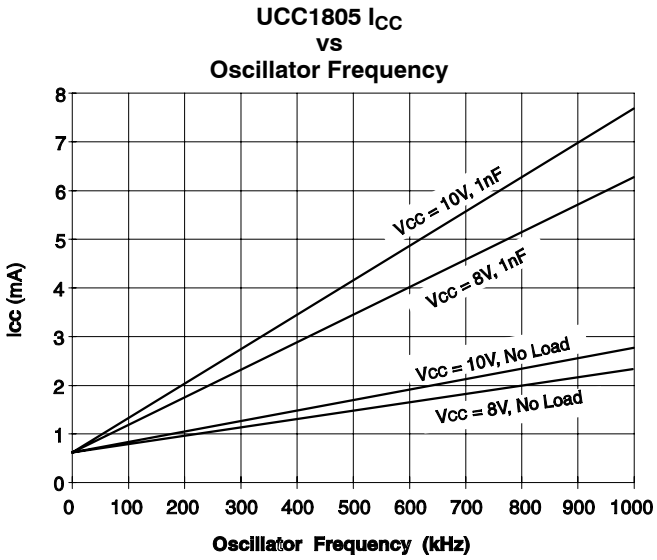


Figure 9

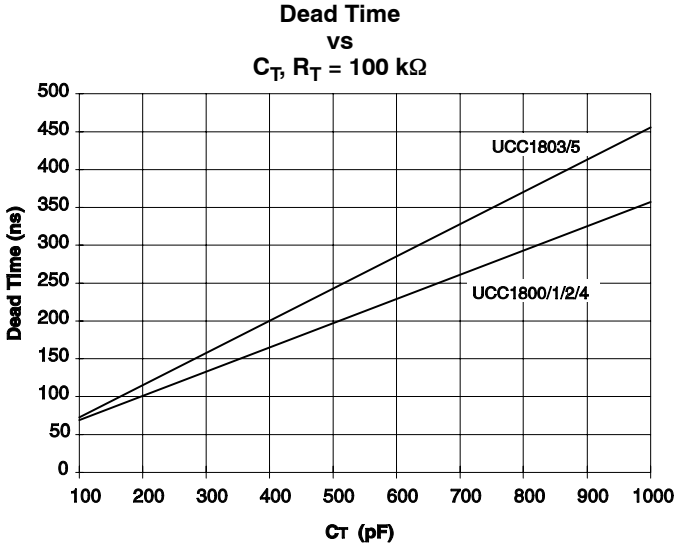


Figure 10

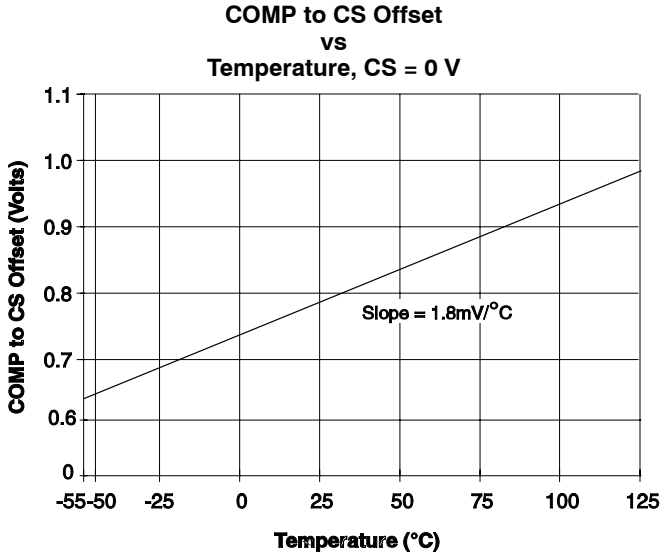
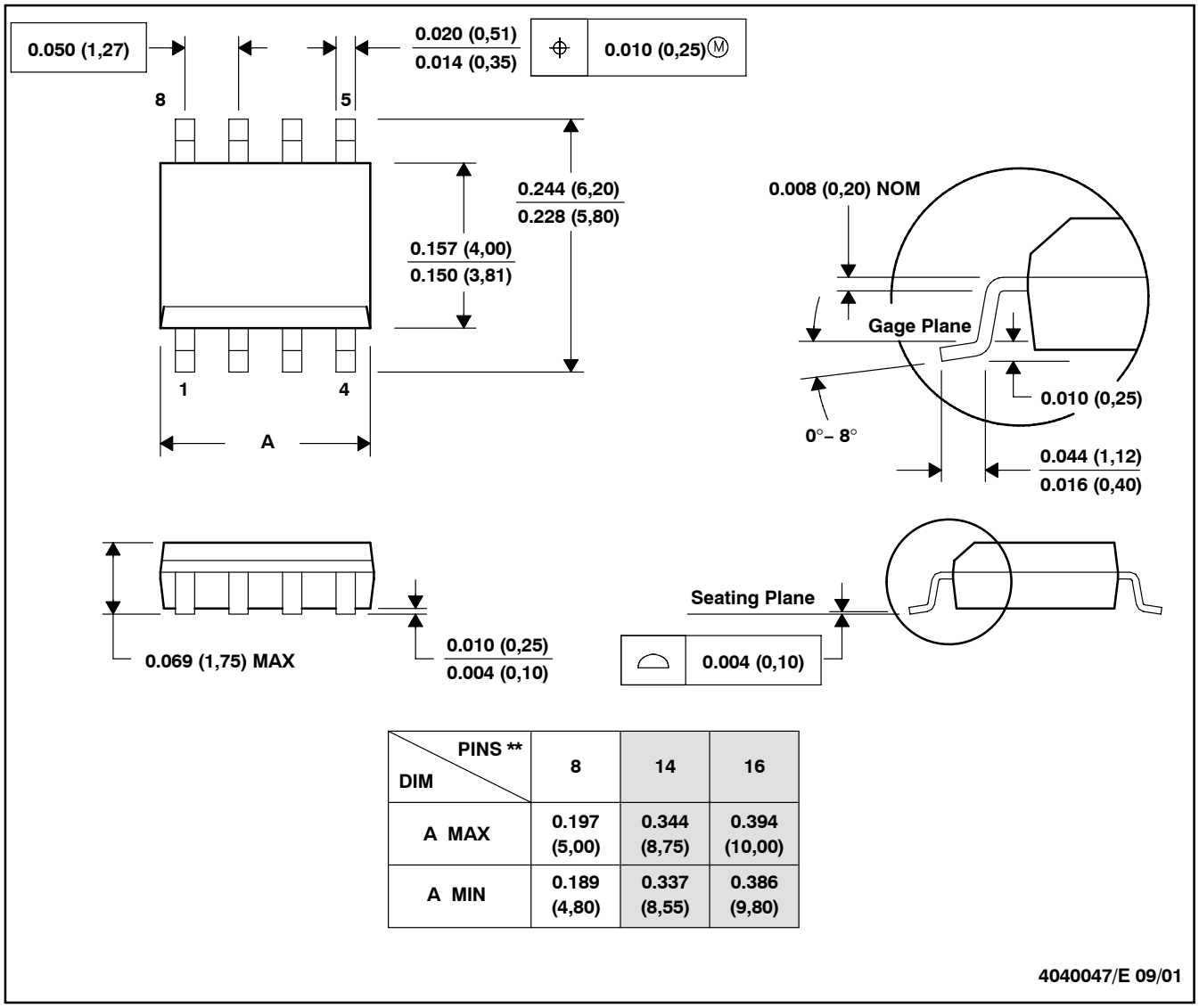


Figure 11

MECHANICAL DATA

D (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

8 PINS SHOWN



DIM \ PINS **	8	14	16
A MAX	0.197 (5,00)	0.344 (8,75)	0.394 (10,00)
A MIN	0.189 (4,80)	0.337 (8,55)	0.386 (9,80)

4040047/E 09/01

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-012

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
UCC2800MDREP	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2800EP
UCC2800MDREP.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2800EP
UCC2800QDREP	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C2800D, C2800DEP) EP
UCC2800QDREP.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C2800D, C2800DEP) EP
UCC2801MDREP	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2801EP
UCC2801MDREP.A	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2801EP
UCC2801QDREP	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-40 to 125	2801EP
UCC2801QDREP.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-40 to 125	2801EP
UCC2802QDREP	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2802EP
UCC2802QDREP.A	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2802EP
UCC2803MDREP	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2803EP
UCC2803MDREP.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2803EP
UCC2803QDREP	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2803EP
UCC2803QDREP.A	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2803EP
UCC2804QDREP	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2804EP
UCC2804QDREP.A	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2804EP
UCC2805QDREP	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2805EP
UCC2805QDREP.A	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2805EP
V62/03624-01XE	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C2800D, C2800DEP) EP
V62/03624-02XE	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-40 to 125	2801EP
V62/03624-03XE	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2802EP
V62/03624-04XE	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2803EP
V62/03624-05XE	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2804EP
V62/03624-06XE	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2805EP
V62/03624-07XE	NRND	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2801EP

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
V62/03624-08XE	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2803EP
V62/03624-09XE	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-250C-1 YEAR	-55 to 125	2800EP

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

OTHER QUALIFIED VERSIONS OF UCC2800-EP, UCC2801-EP, UCC2802-EP, UCC2803-EP, UCC2804-EP, UCC2805-EP :

- Catalog : UCC2800, UCC2801, UCC2802, UCC2803, UCC2804, UCC2805
- Automotive : UCC2800-Q1, UCC2801-Q1, UCC2802-Q1, UCC2803-Q1, UCC2804-Q1, UCC2805-Q1

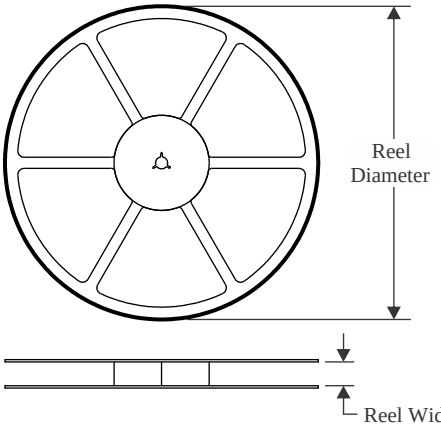
- Military : UCC2802M

NOTE: Qualified Version Definitions:

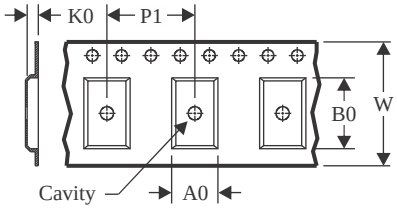
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

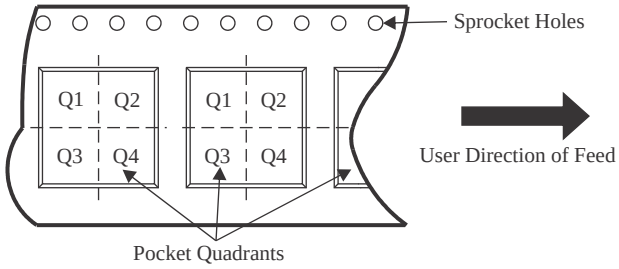


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

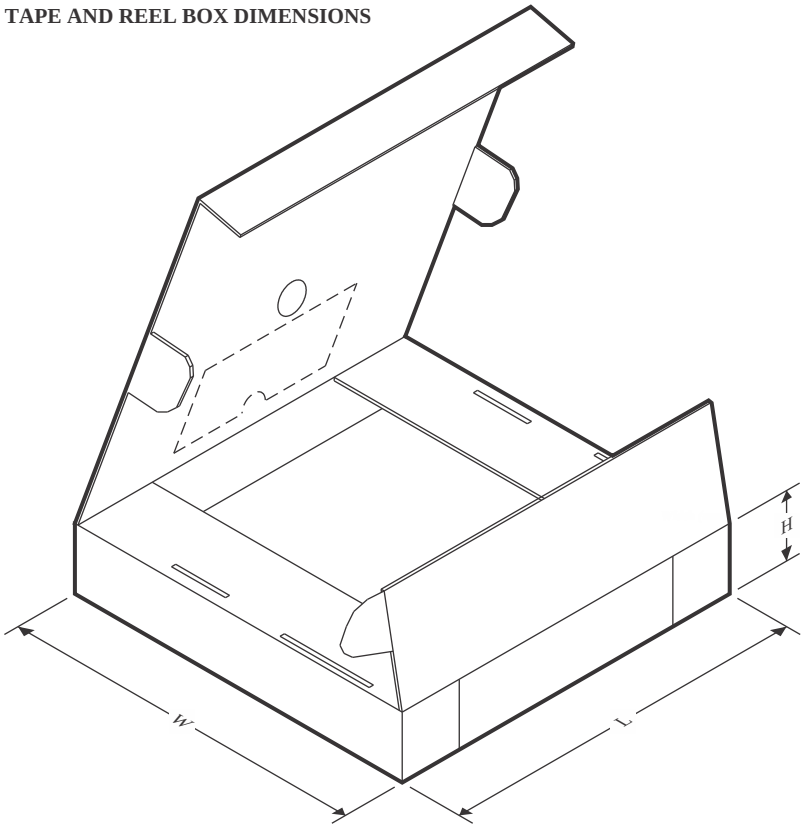
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UCC2800MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2800MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2800QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2801MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2801QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2801QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2802QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2803MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2803MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2803QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2804QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UCC2805QDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

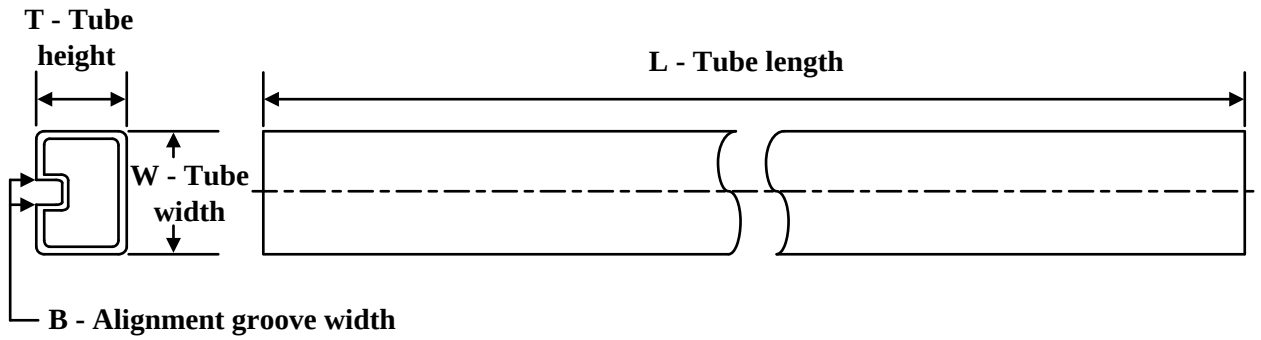
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UCC2800MDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2800MDREP	SOIC	D	8	2500	353.0	353.0	32.0
UCC2800QDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2801MDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2801QDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2801QDREP	SOIC	D	8	2500	353.0	353.0	32.0
UCC2802QDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2803MDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2803MDREP	SOIC	D	8	2500	353.0	353.0	32.0
UCC2803QDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2804QDREP	SOIC	D	8	2500	350.0	350.0	43.0
UCC2805QDREP	SOIC	D	8	2500	350.0	350.0	43.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
UCC2800MDREP	D	SOIC	8	2500	506.6	8	3940	4.32
UCC2800MDREP.A	D	SOIC	8	2500	506.6	8	3940	4.32
UCC2801QDREP	D	SOIC	8	2500	506.6	8	3940	4.32
UCC2801QDREP.A	D	SOIC	8	2500	506.6	8	3940	4.32
UCC2803MDREP	D	SOIC	8	2500	506.6	8	3940	4.32
UCC2803MDREP.A	D	SOIC	8	2500	506.6	8	3940	4.32
V62/03624-02XE	D	SOIC	8	2500	506.6	8	3940	4.32
V62/03624-08XE	D	SOIC	8	2500	506.6	8	3940	4.32
V62/03624-09XE	D	SOIC	8	2500	506.6	8	3940	4.32

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